NSN 5961-01-312-7565

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Inclosure Material:

Plastic

Overall Length:

0.472 inches

Terminal Length:

0.500 inches

Overall Height:

0.110 inches

Overall Width:

0.314 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Mounting Method:

Terminal and unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

70.0 breakdown voltage, collector-to-base, emitter open and 50.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown

voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

Between 800.00 milliamperes source cutoff current and 800.00 milliamperes source cutoff current

Power Rating Per Characteristic:

5.0 watts small-signal input power, common-collector

Transfer Ratio:

40.0 static forward current transfer ratio, common-emitter and 240.0 static forward current transfer ratio, common-emitter

Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

3 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0